NSN 5961-01-578-1805

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-578-1805 **Inclosure Material:** Glass **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Mounting Method:** Terminal Voltage Rating In Volts Per Characteristic: 26.7 breakdown voltage, dc and 29.5 breakdown voltage, dc **Current Rating Per Characteristic:** 12.80 amperes peak pulse current **Power Rating Per Characteristic:** 500.0 watts peak pulse output power **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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